

## Description

The IS281x series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar phototransistor detector in a plastic SSOP4 package with different lead forming options.

With the robust coplanar double mold structure, IS281x series provide the most stable isolation feature.

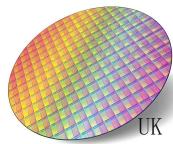
## Features

- High isolation 3750 VRMS
- CTR flexibility available see order information
- DC input with transistor output
- Operating temperature range - 55 °C to 110 °C
- REACH compliance
- Halogen free
- MSL class 1

## Applications

- Switch mode power supplies
- Programmable controllers
- Household appliances
- Office equipment





SSOP4, DC Input, Photo Transistor Couple

## ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT	NOTE
INPUT				
Forward Current	$I_F$	60	mA	
Peak Forward Current	$I_{FP}$	1	A	1
Reverse Voltage	$V_R$	6	V	
Input Power Dissipation	$P_I$	100	mW	
OUTPUT				
Collector - Emitter Voltage	$V_{CEO}$	80	V	
Emitter - Collector Voltage	$V_{ECO}$	7	V	
Collector Current	$I_C$	50	mA	
Output Power Dissipation	$P_O$	150	mW	
COMMON				
Total Power Dissipation	$P_{tot}$	200	mW	
Isolation Voltage	$V_{iso}$	3750	Vrms	2
Operating Temperature	$T_{opr}$	-55~110	°C	
Storage Temperature	$T_{stg}$	-55~125	°C	
Soldering Temperature	$T_{sol}$	260	°C	

Note 1. 100μs pulse, 100Hz frequency

Note 2. AC For 1 Minute, R.H. = 40 ~ 60%

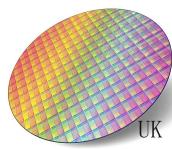
SSOP4, DC Input, Photo Transistor Couple

 ELECTRICAL OPTICAL CHARACTERISTICS at  $T_a=25^\circ C$ 

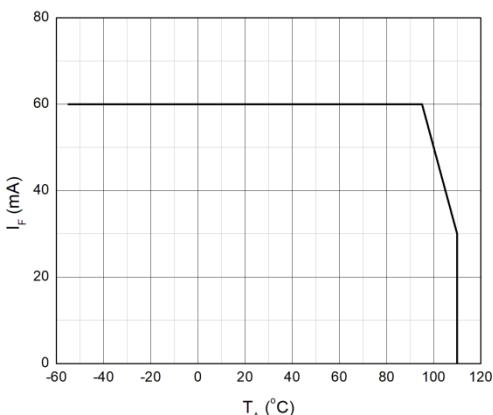
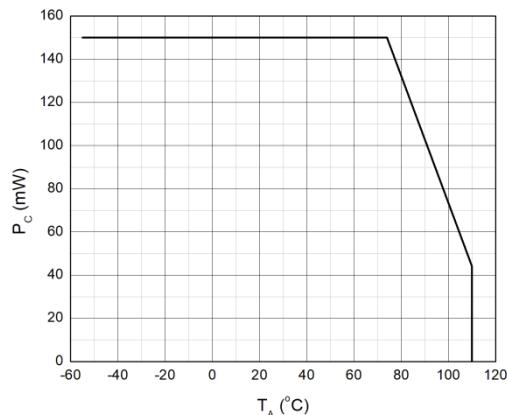
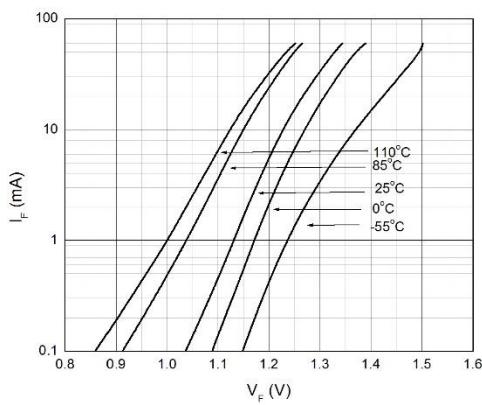
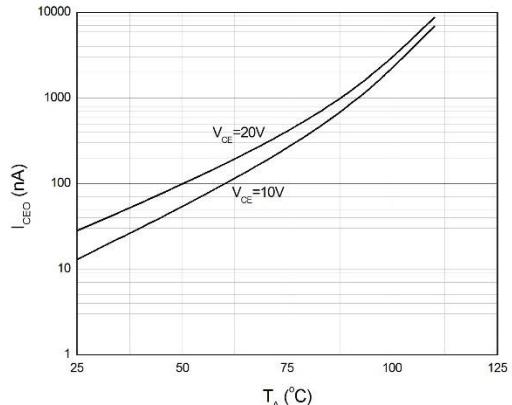
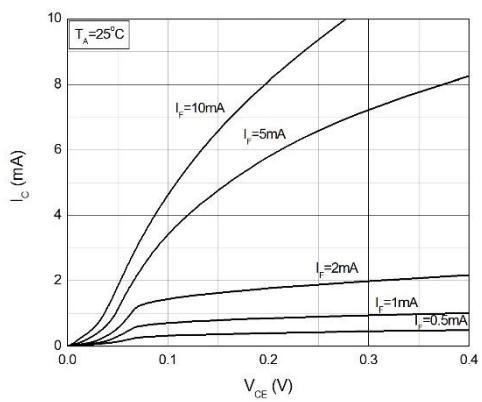
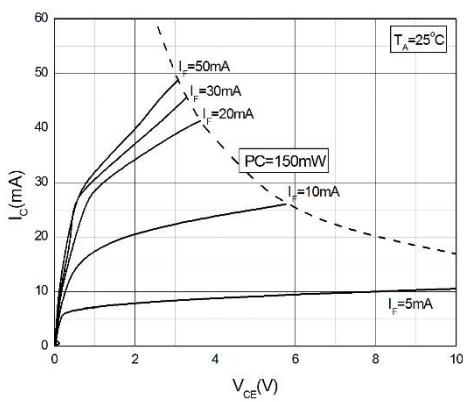
PARAMETER	SYMBOL	MIN	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
INPUT							
Forward Voltage	$V_F$	-	-	1.4	V	$IF=10mA$	
Reverse Current	$I_R$	-	-	10	$\mu A$	$VR=6V$	
Input Capacitance	$C_{in}$	-	10	-	pF	$V=0, f=1kHz$	
OUTPUT							
Collector Dark Current	$I_{CEO}$	-	-	100	nA	$VCE=20V, IF=0$	
Collector-Emitter Breakdown Voltage	$BV_{CEO}$	80	-	-	V	$IC=0.1mA, IF=0$	
Emitter-Collector Breakdown Voltage	$BV_{ECO}$	7	-	-	V	$IE=0.1mA, IF=0$	
TRANSFER CHARACTERISTICS							
Current Transfer Ratio	281	CTR	50	-	600	% IF=5mA, VCE=5V	
	281GB		100	-	600		
	281GR		100	-	300		
	281GRL		100	-	200		
	281GRH		150	-	300		
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	-	0.1	0.2	V	$IF=10mA, IC=1mA$	
Isolation Resistance	$R_{ISO}$	$10^{12}$	$10^{14}$	-	$\Omega$	$DC500V, 40 \sim 60\% R.H.$	
Floating Capacitance	$C_{IO}$	-	0.4	1	pF	$V=0, f=1MHz$	
Response Time (Rise)	$tr$	-	3	18	$\mu s$	$VCE=2V, IC=2mA$ $RL=100\Omega$	3
Response Time (Fall)	$tf$	-	4	18	$\mu s$		3
Cut-off Frequency	$fc$	-	80	-	kHz	$VCE=2V, IC=2mA$ $RL=100\Omega, -3dB$	4

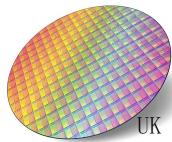
Note 3. Fig.12&amp;13

Note 4. Fig.14

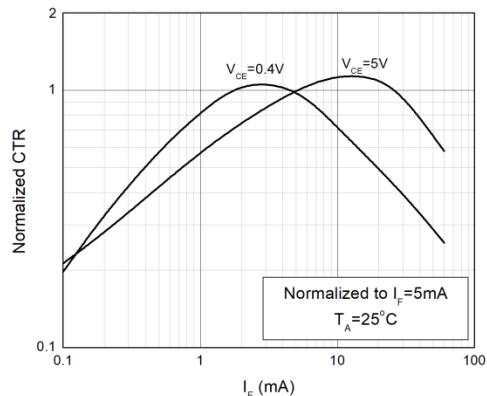
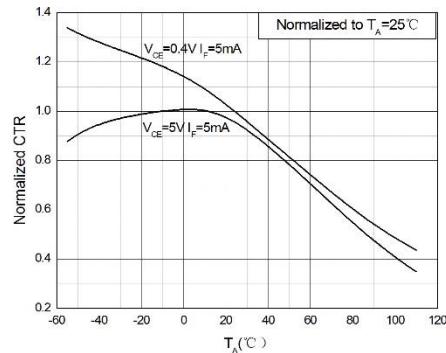
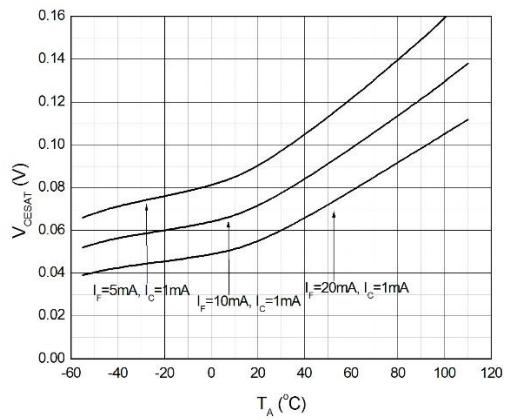
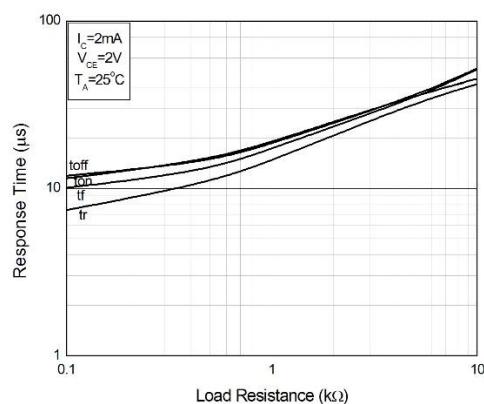
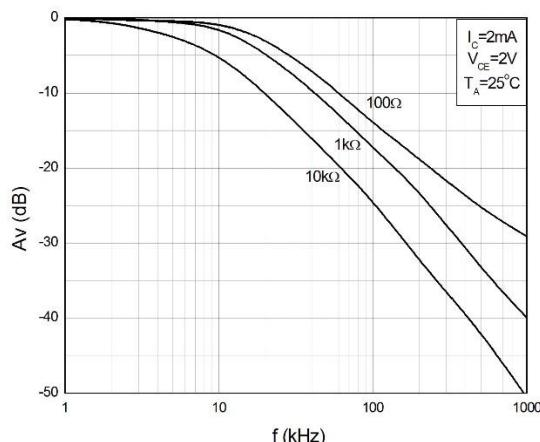


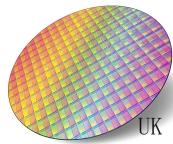
## CHARACTERISTIC CURVES

**Fig.1 Forward Current  
vs. Ambient Temperature****Fig.2 Collector Power Dissipation  
vs. Ambient Temperature****Fig.3 Forward Current  
vs. Forward Voltage****Fig.4 Collector Dark Current  
vs. Ambient Temperature****Fig.5 Collector Current  
vs. Collector-emitter Voltage****Fig.6 Collector Current  
vs. Collector-emitter Voltage**



## CHARACTERISTIC CURVES

**Fig.7 Normalized Current Transfer Ratio vs. Forward Current****Fig.8 Normalized Current Transfer Ratio vs. Ambient Temperature****Fig.9 Collector-emitter Saturation Voltage vs. Ambient Temperature****Fig.10 Switching Time vs. Load Resistance****Fig.11 Frequency Response**



## TEST CIRCUITS

Fig.12 Test Circuits of Response Time

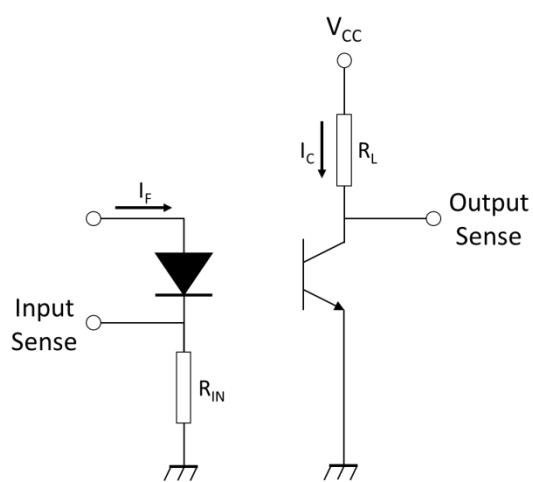


Fig.13 Curves of Response Time

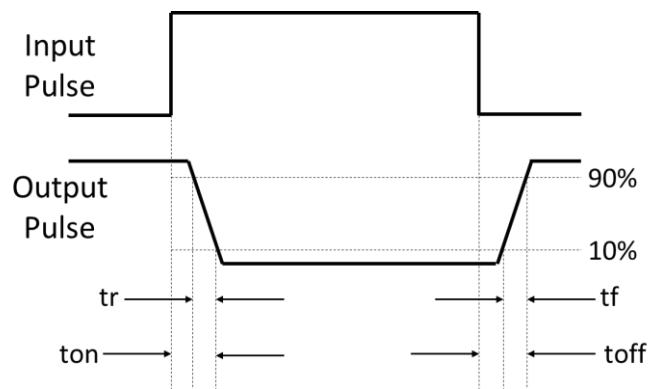
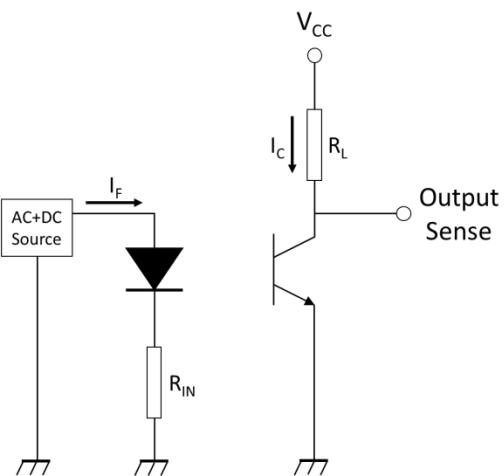
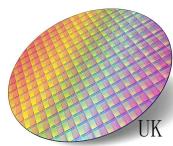


Fig.14 Test Circuits of Frequency Response





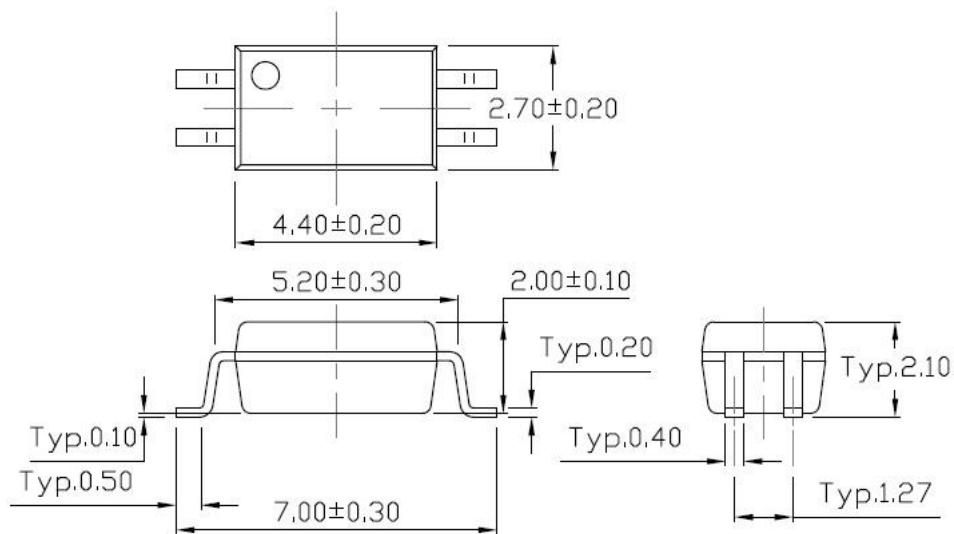
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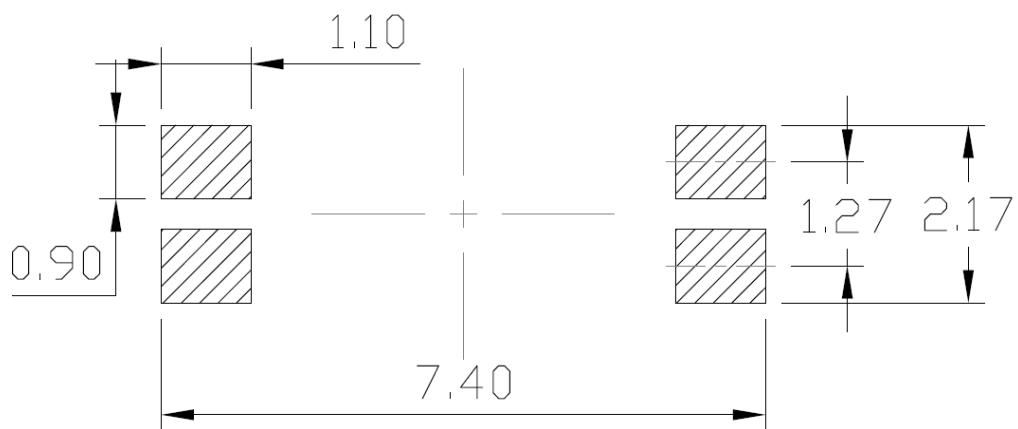
IS281x Series

SSOP4, DC Input, Photo Transistor Couple

### PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)



### Recommended Solder Mask (Dimensions in mm unless otherwise stated)





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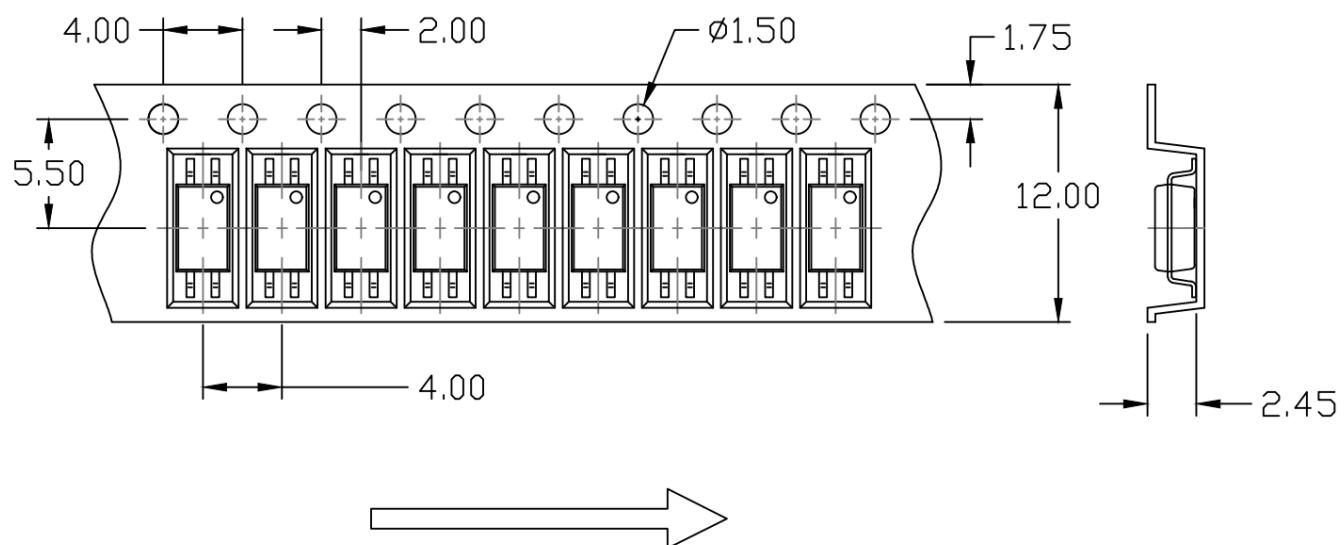
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IS281x Series

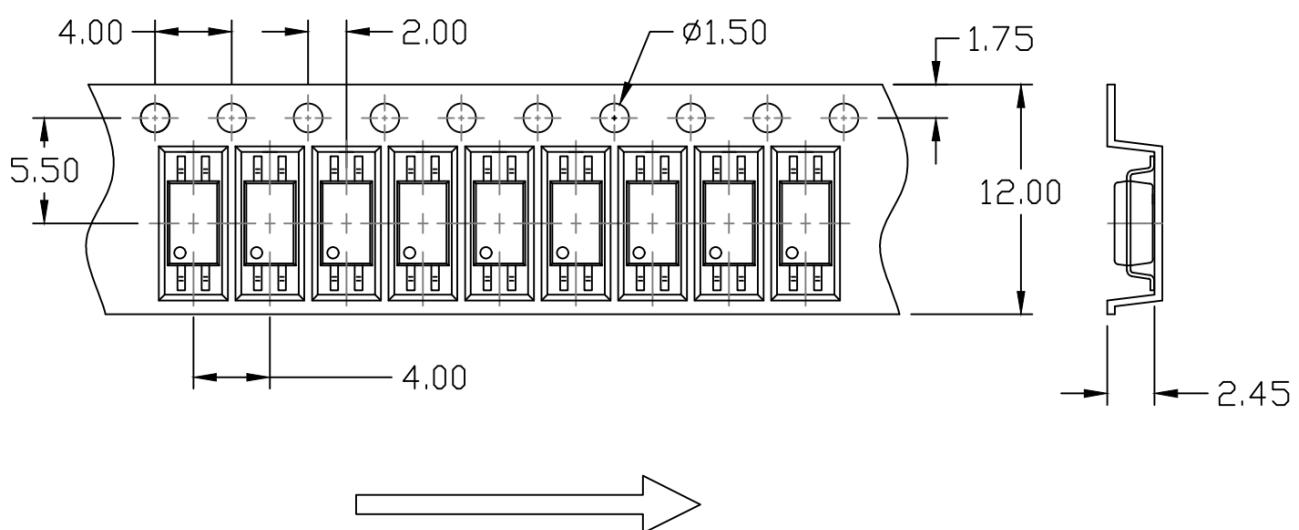
SSOP4, DC Input, Photo Transistor Couple

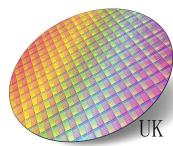
**CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)**

**Option T1**



**Option T2**





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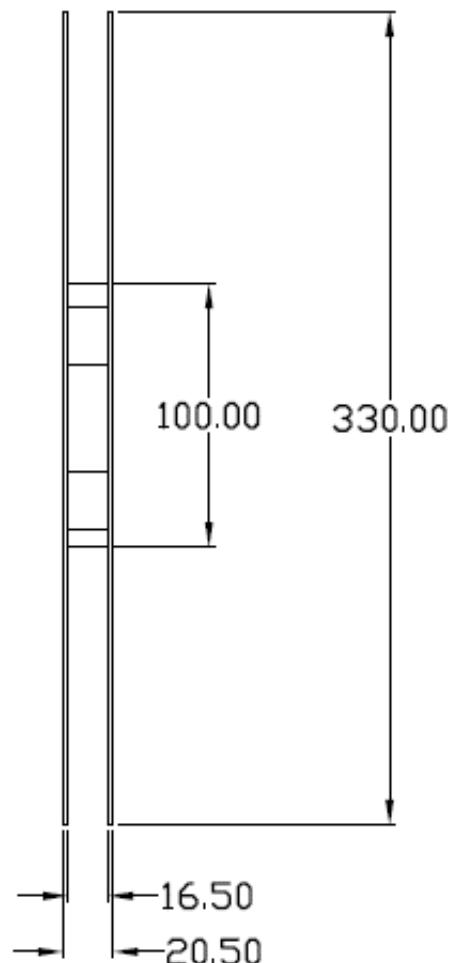
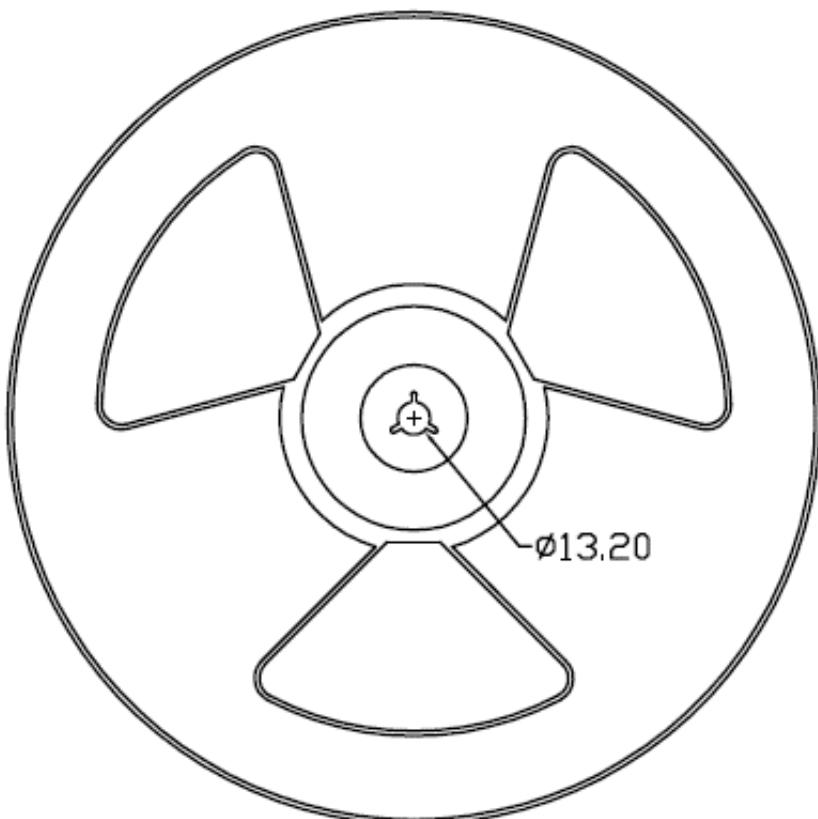
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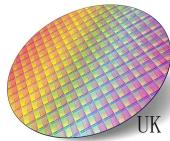
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**REEL SPECIFICATIONS (Dimensions in mm unless otherwise stated)**

**Option T1 & T2**





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## ORDERING AND MARKING INFORMATION

### MARKING INFORMATION

	<p><b>THP:</b> Part Number <b>X :</b> CTR grade, None/GB/GR/GRL/GRH <b>I :</b> denotes Company Abbr. <b>Y :</b> denotes 1 digit Year code, Y=Year (A-2010, B-2011, …, K-2020, L-2021) <b>WW:</b> denotes 2 digit Week code</p>
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### ORDERING INFORMATION

**IS281x**

**IS281:** Part Number

**X:** CTR grade, None/GB/GR/GRL/GRH

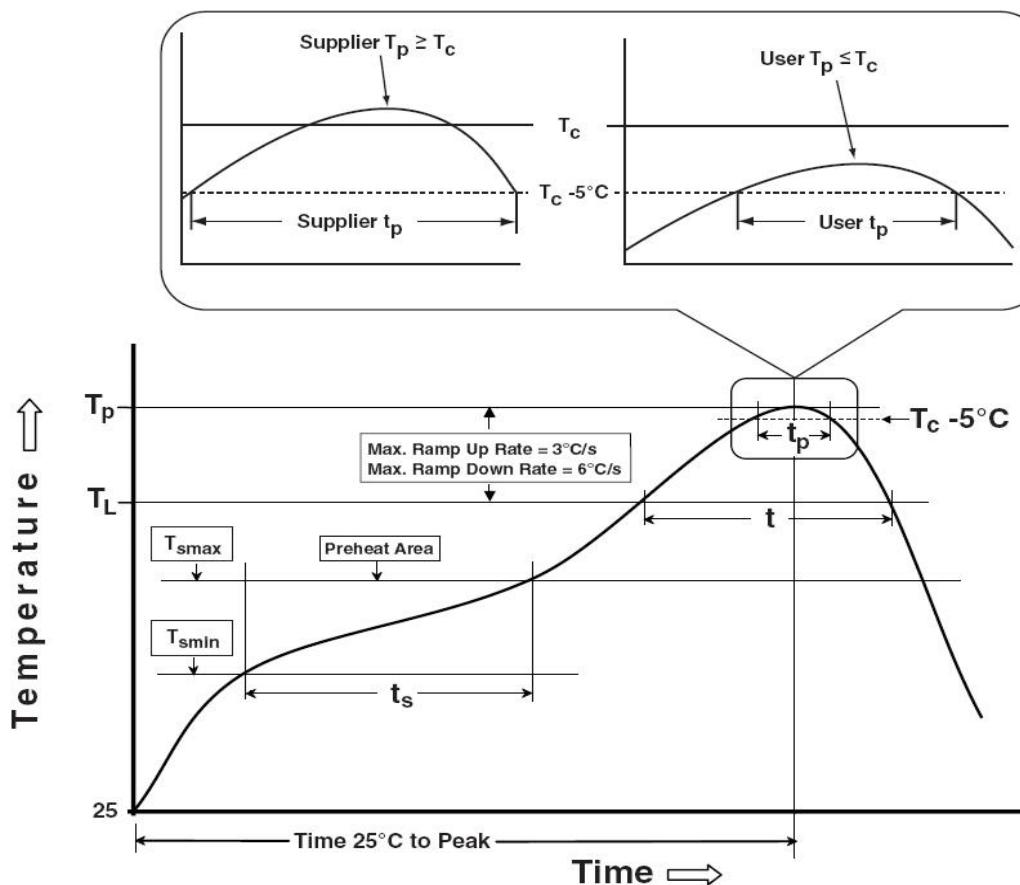
### PACKING QUANTITY

Option	Quantity	Quantity – Inner box	Quantity – Outer box
T1	3000 Units/Reel	2 Reels/Inner box	5 Inner box/Outer box = 30k Units
T2	3000 Units/Reel	2 Reels/Inner box	5 Inner box/Outer box = 30k Units



## REFLOW INFORMATION

## REFLOW PROFILE



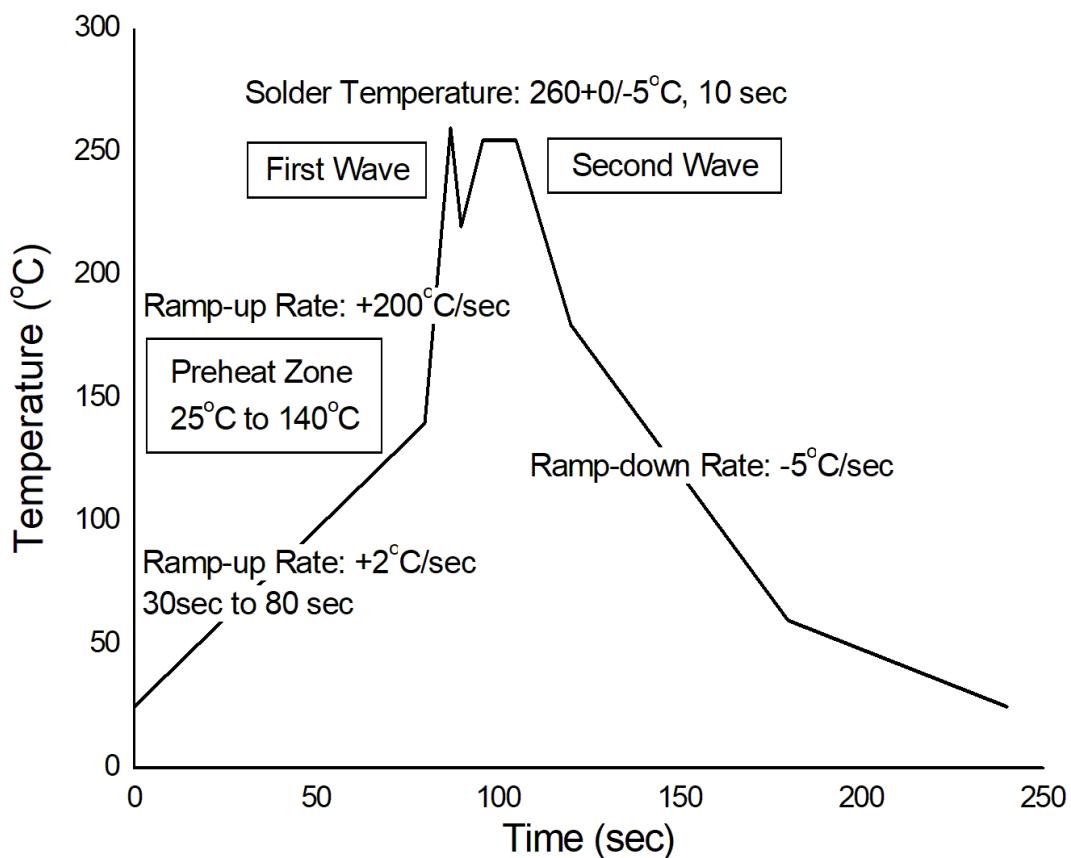
IPC-020d-5-1

Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. ( $T_{smin}$ )	100	150°C
Temperature Max. ( $T_{smax}$ )	150	200°C
Time ( $t_s$ ) from ( $T_{smin}$ to $T_{smax}$ )	60-120 seconds	60-120 seconds
Ramp-up Rate ( $t_L$ to $t_p$ )	3°C/second max.	3°C/second max.
Liquidous Temperature ( $T_L$ )	183°C	217°C
Time ( $t_L$ ) Maintained Above ( $T_L$ )	60 – 150 seconds	60 – 150 seconds
Peak Body Package Temperature	235°C +0°C / -5°C	260°C +0°C / -5°C
Time ( $t_p$ ) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate ( $T_p$ to $T_L$ )	6°C/second max	6°C/second max
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.



## TEMPERATURE PROFILE OF SOLDERING

## WAVE SOLDERING (JESD22-A111 COMPLIANT)



## HAND SOLDERING BY SOLDERING IRON

Soldering Temperature	380+0/-5°C
Soldering Time	3 sec max.

- One time soldering is recommended for all soldering method.
- Do not solder more than three times for IR reflow soldering.

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- The characteristic curves shown in this datasheet are representing typical performance which are not guaranteed.
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- This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or lifesaving applications or any other application which can result in human injury or death.
- Please contact ASG sales agent for special application request.
- Immerge unit's body in solder paste is not recommended.
- Parameters provided in datasheets may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated in each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify ASG's terms and conditions of purchase, including but not limited to the warranty expressed therein.
- Discoloration might be occurred on the package surface after soldering, reflow or long-time use. It neither impacts the performance nor reliability.